

**Description**

The SX9926A uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

**General Features**

$V_{DS} = 20V$   $I_D = 8.2A$

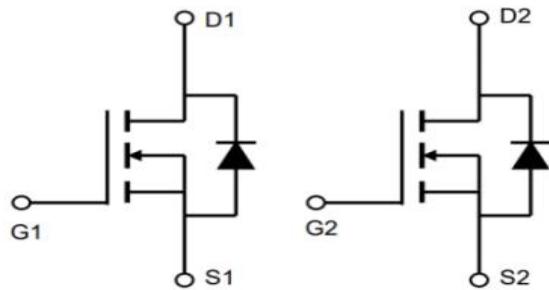
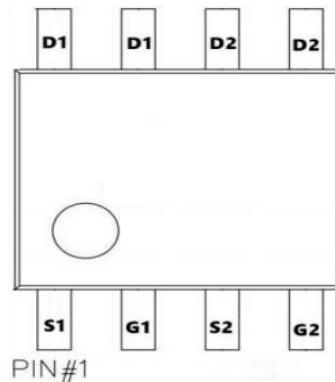
$R_{DS(ON)} < 23m\Omega$  @  $V_{GS}=4.5V$

**Application**

Battery protection

Load switch

Uninterruptible power supply

**SOP-8L****Absolute Maximum Ratings ( $T_c=25^\circ C$  unless otherwise noted)**

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	20	V
$V_{GS}$	Gate-Source Voltage	$\pm 12$	V
$I_D @ T_A=25^\circ C$	Continuous Drain Current, $V_{GS} @ 4.5V^1$	8.2	A
$I_D @ T_A=70^\circ C$	Continuous Drain Current, $V_{GS} @ 4.5V^1$	5.8	A
$I_{DM}$	Pulsed Drain Current <sup>2</sup>	30.6	A
$P_D @ T_A=25^\circ C$	Total Power Dissipation <sup>3</sup>	1.25	W
$T_{STG}$	Storage Temperature Range	-55 to 150	°C
$T_J$	Operating Junction Temperature Range	-55 to 150	°C
$R_{\theta JA}$	Thermal Resistance Junction-ambient <sup>1</sup>	85	°C/W
$R_{\theta JC}$	Thermal Resistance Junction-Case <sup>1</sup>	74	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)**

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$ , $I_D=250\mu\text{A}$	20	22	-	V
IDSS	Zero Gate Voltage Drain Current	$V_{DS}=20\text{V}$ , $V_{GS}=0\text{V}$ ,	-	-	1.0	$\mu\text{A}$
IGSS	Gate to Body Leakage Current	$V_{DS}=0\text{V}$ , $V_{GS}=\pm 12\text{V}$	-	-	$\pm 100$	nA
VGS(th)	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D=250\mu\text{A}$	0.4	0.7	1.0	V
RDS(on)	Static Drain-Source on-Resistance note2	$V_{GS}=4.5\text{V}$ , $I_D=4.5\text{A}$	-	17	23	$\text{m}\Omega$
		$V_{GS}=2.5\text{V}$ , $I_D=2.5\text{A}$	-	21	28	
Ciss	Input Capacitance	$V_{DS}=10\text{V}$ , $V_{GS}=0\text{V}$ , $f=1.0\text{MHz}$	-	358	-	pF
Coss	Output Capacitance		-	69.3	-	pF
Crss	Reverse Transfer Capacitance		-	58.5	-	pF
Qg	Total Gate Charge		-	5.6	-	nC
Qgs	Gate-Source Charge	$V_{DS}=10\text{V}$ , $I_D=3\text{A}$ , $V_{GS}=4.5\text{V}$	-	0.8	-	nC
Qgd	Gate-Drain("Miller") Charge		-	1	-	nC
td(on)	Turn-on Delay Time		-	16	-	ns
tr	Turn-on Rise Time		-	51	-	ns
td(off)	Turn-off Delay Time	$V_{DS}=10\text{V}$ , $I_D=6\text{A}$ , $R_{GEN}=3\Omega$ , $V_{GS}=4.5\text{V}$	-	21	-	ns
tf	Turn-off Fall Time		-	19	-	ns
IS	Maximum Continuous Drain to Source Diode Forward Current	-	-	6	A	
ISM	Maximum Pulsed Drain to Source Diode Forward Current	-	-	24	A	
VSD	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}$ , $I_S=6\text{A}$	-	-	1.2	V

**Note :**

- 1、The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width  $\leq 300\mu\text{s}$  , duty cycle  $\leq 2\%$
- 3、The power dissipation is limited by  $150^\circ\text{C}$ junction temperature
- 4、The data is theoretically the same as  $I_D$  and  $I_{DM}$  , in real applications , should be limited by total power dissipation.

## Typical Characteristics

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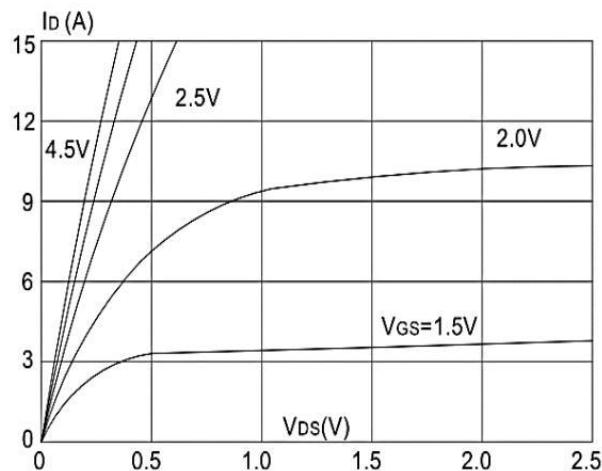


Figure 1: Output Characteristics

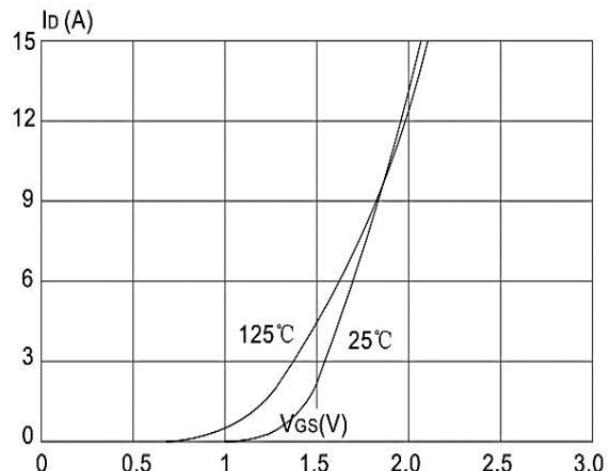


Figure 2: Typical Transfer Characteristics

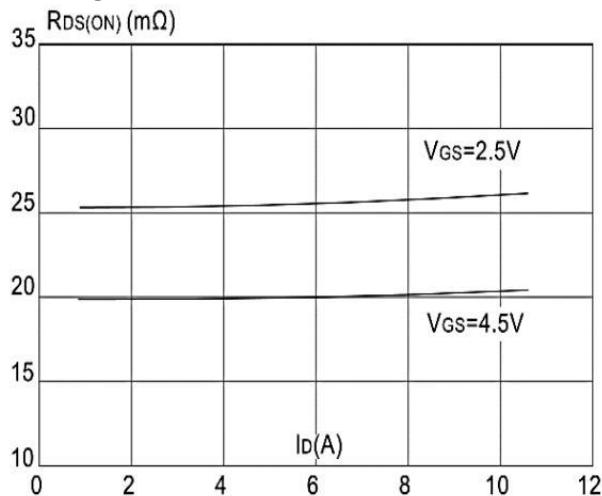


Figure 3: On-resistance vs. Drain Current

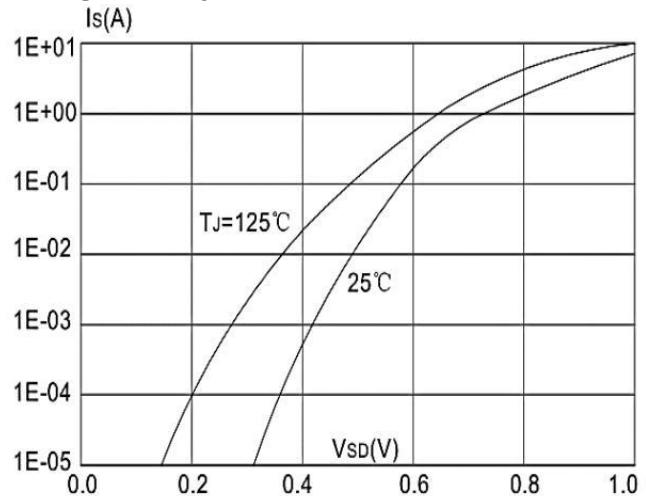


Figure 4: Body Diode Characteristics

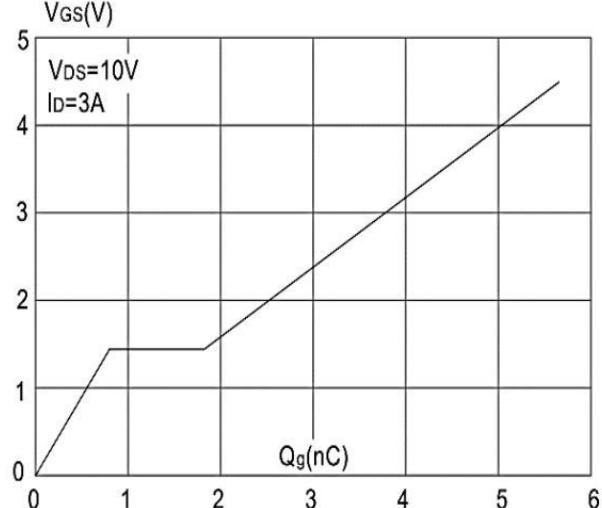


Figure 5: Gate Charge Characteristics

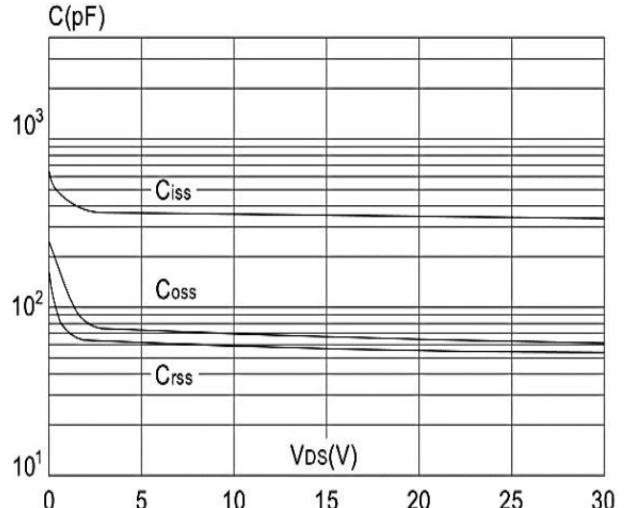


Figure 6: Capacitance Characteristics

### Typical Characteristics

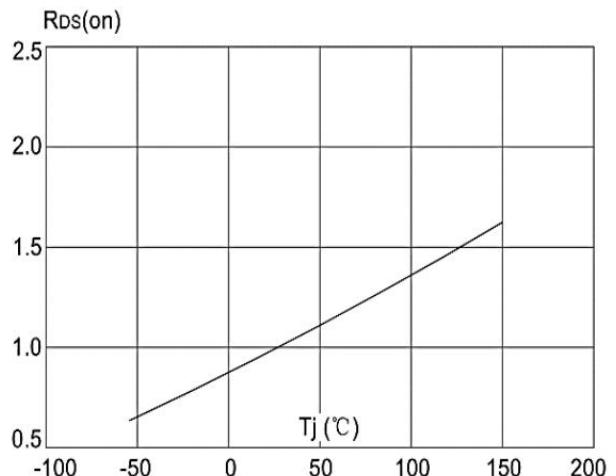
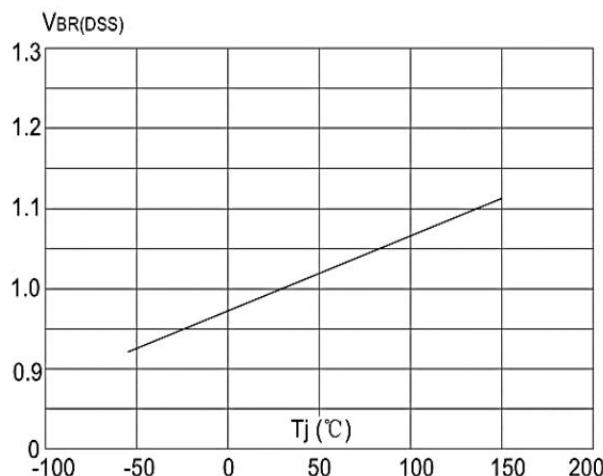


Figure 7: Normalized Breakdown Voltage vs Junction Temperature

Figure 8: Normalized on Resistance vs. Junction Temperature

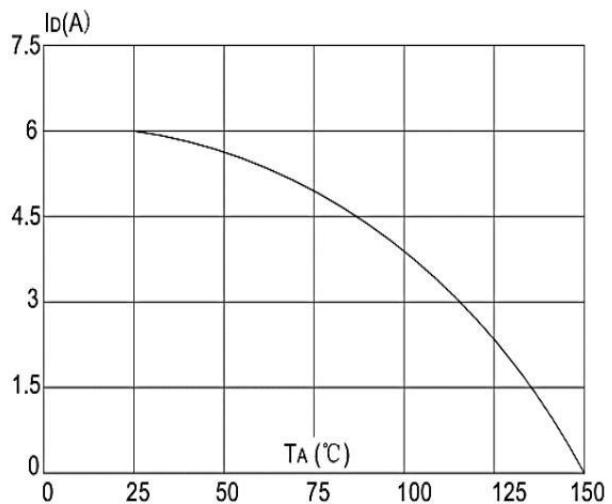
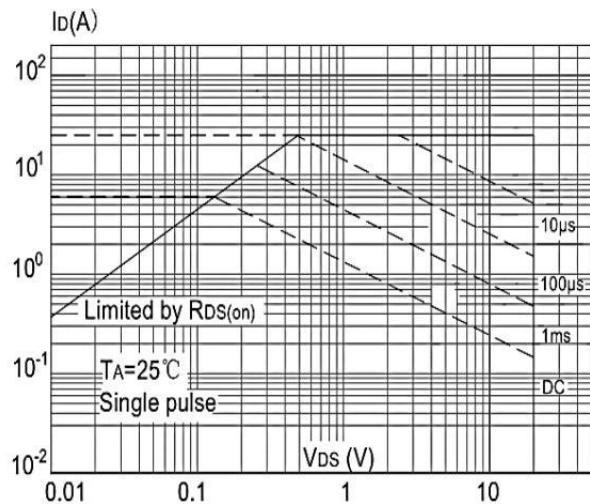


Figure 9: Maximum Safe Operating Area

Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

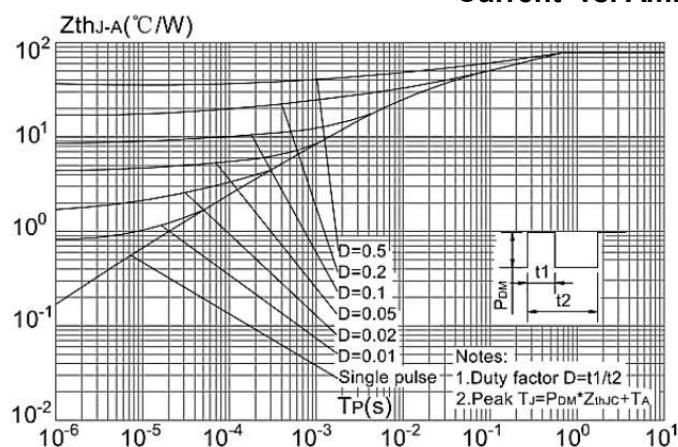
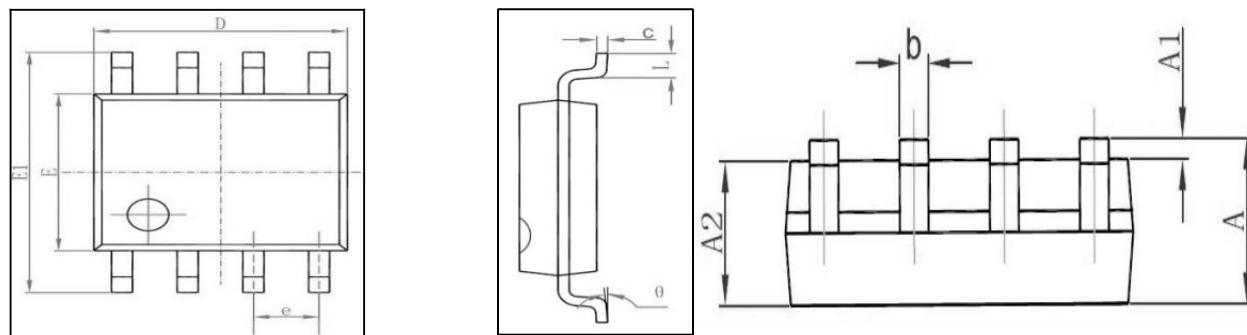
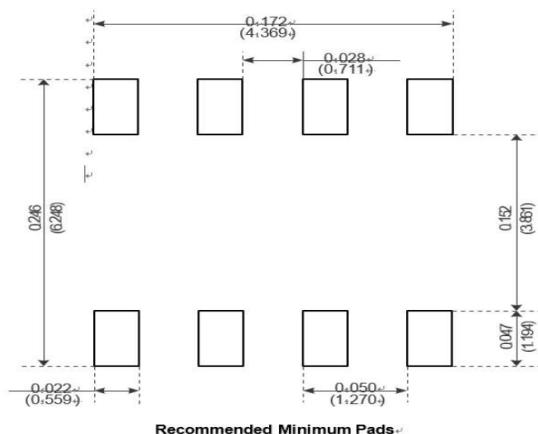


Figure 11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

## Package Mechanical Data-SOP-8L



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270 (BSC)		0.050 (BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



### Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	SOP-8L		3000